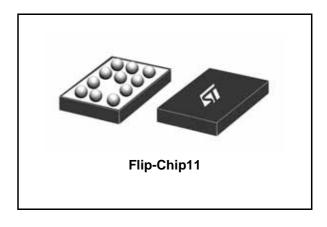




Low voltage $0.3\Omega\,\text{max}$ dual SPDT switch with break-before-make feature and 15KV ESD protection

Features

- Wide operating voltage range: V_{CC} (Opr) = 1.65 V to 4.8 V
- Low power dissipation: $I_{CC} = 0.2 \mu A \text{ (max) at } T_A = 85^{\circ}C$
- Low ON resistance V_{IN} = 0V:
 - R $_{ON}$ = 0.4 Ω (max T $_{A}$ = 25°C) at V $_{CC}$ = 2.25 V
 - R_{ON} = 0.35 Ω (max T_A = 25°C) at V_{CC} = 3.0 V
 - R $_{ON}$ = 0.30 Ω (max T $_{A}$ = 25°C) at V $_{CC}$ = 4.3 V
- Separate supply voltage for switch and control pin
- Separate control pin for each switch
- Latch-up performance exceeds 100 mA per JESD 78, class II
- ESD performance tested on common channels (D1 and D2 pins)
 - 9 kV IEC-61000-4-2 ESD, contact discharge
 - 15 kV IEC-61000-4-2 ESD, air gap discharge
- ESD performance tested on all other pins
 - 8 kV IEC-61000-4-2 ESD, contact discharge
 - 500 V machine model (JESD22 A115-A)
 - 1500 V charged-device model (JESD22 C101)
 - 8 kV IEC-61000-4-2 ESD, air gap discharge



Description

The STG4259 is a high-speed CMOS low voltage dual analog SPDT (single pole dual throw) switch or 2:1 multiplexer/ demultiplexer switch fabricated in silicon gate C^2 MOS technology. It is designed to operate from 1.65 V to 4.8 V, making this device ideal for portable applications. It offers low ON resistance $(0.30~\Omega)$ at V_{CC} = 4.3 V. The SEL inputs are provided to control the switches.

The switch S1 is ON (connected to common port D) when the SEL input is held high and OFF (high impedance state exists between the two ports) when SEL is held low; the switch S2 is ON (it is connected to common port D) when the SEL input is held low and OFF (high impedance state exist between the two ports) when SEL is held high.

Additional key features are fast switching speed, break-before-make delay time and ultra low power consumption. All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Table 1. Device summary

Order code	Package	Packing
STG4259BJR	Flip-Chip11	Tape and Reel

Contents STG4259

Contents

1	Logic diagram and pin-out information
2	Maximum rating
3	Electrical characteristics
4	Test circuits
5	Package mechanical data
6	Revision history

1 Logic diagram and pin-out information

Figure 1. Functional diagram

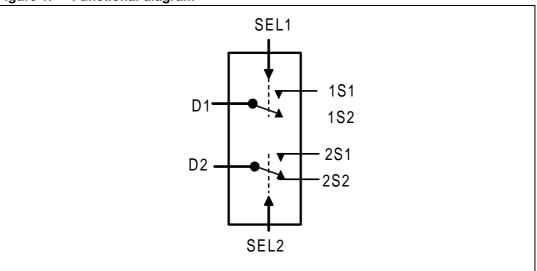


Figure 2. Input equivalent circuit

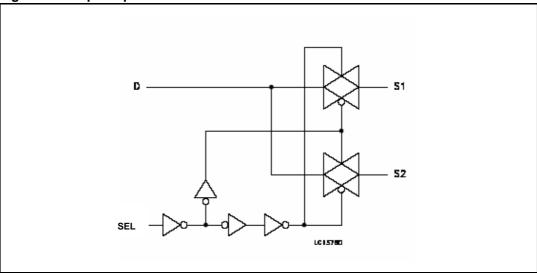


Table 2. Truth table

SELn	Switch nS1	Switch nS2
Н	ON	OFF ⁽¹⁾
L	OFF ⁽¹⁾	ON

1. High impedance

Figure 3. Pin connection (bump side view)

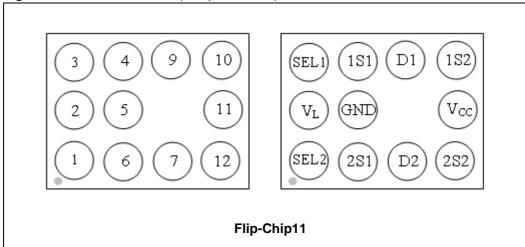


Table 3. Pin description

Table 6. Thi description		
Flip-Chip11	Symbol	Name and function
4, 10, 6, 12	1S1, 1S2, 2S1, 2S2	Independent channels
9, 7	D1, D2	Common channels
3, 1	SEL1, SEL2	Control
11	V _{CC}	Positive supply voltage
2	V_{L}	Logic supply voltage
5	GND	Ground (0V)

STG4259 Maximum rating

2 Maximum rating

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to 5.5	V
V _L	Logic supply voltage	-0.5 to 5.5	V
VI	DC input voltage	-0.5 to V _{CC} + 0.5	V
V_{IC}	DC control input voltage	-0.5 to V _L + 0.5	V
Vo	DC output voltage	-0.5 to V _{CC} + 0.5	V
I _{IKC}	DC input diode current on control pin (V _{SEL} < 0V)	- 50	mA
I _{IK}	DC input diode current (V _{SEL} < 0V)	± 50	mA
I _{OK}	DC output diode current	± 20	mA
I _O	DC output current	± 300	mA
I _{OP}	DC output current peak (pulse at 1ms, 10% duty cycle)	± 500	mA
I _{CC} or I _{GND}	DC V _{CC} or ground current	± 100	mA
P_{D}	Power dissipation at T _A = 70°C ⁽¹⁾	500	mW
T _{stg}	Storage temperature	-50 to 105	°C
T_L	Lead temperature (10 sec)	260	°C

^{1.} Derate above 70°C by 18.5mW/C

Maximum rating STG4259

Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit	
V _{CC}	Supply voltage (1)		1.65 to 4.8	V
V _L	Logic supply voltage		1.65 to V _{CC}	V
VI	Input voltage		0 to V _{CC}	V
V _{IC}	Control input voltage	0 to V _L	V	
Vo	Output voltage		0 to V _{CC}	V
T _{op}	Operating temperature		-40 to 85	°C
44/4.	Input rise and fall time control	V _L = 1.65 V to 2.7 V	0 to 20	
dt/dv	input	V _L = 3.0 to 4.8 V	0 to 10	ns/V

^{1.} Truth table guaranteed: 1.65 V to 4.8 V

3 Electrical characteristics

Table 6. DC specifications

			Test conditi	ons							
Symbol	Parameter	V _{CC}	V _L		т,	₄ = 25°	°C	-40 to 85°C		Unit	
		(V)	(V)		Min	Тур	Max	Min	Max		
			1.65 - 1.95		1.25			1.25			
	High level	1.65 -	2.3 - 2.7		1.75			1.75		.,	
V_{IH}	input voltage	4.3	3.0 - 3.6		2.35			2.35		V	
			4.3		2.8			2.8			
			1.65 - 1.95				0.6		0.6		
\/	Low level input	1.65 -	2.3 - 2.7				0.8		0.8	V	
V_{IL}	voltage	4.3	3.0 - 3.6				1.05		1.05	V	
			4.3				1.5		1.5		
		1.8				0.49	0.65		0.85		
		2.25		1	$V_S = 0 V to$		0.30	0.40		0.50	
R _{ON}	ON resistance	3	1.65 - 4.8	V _{CC}		0.25	0.35		0.45	Ω	
		3.7		$I_{S} = 100 \text{ mA}$		0.22	0.32		0.42		
		4.3				0.21	0.30		0.40		
		1.8				5					
	ON resistance	2.25		$V_S = 0 V to$		3					
ΔR_{ON}	match between	3	1.65 - 4.8	V _{CC}		3				mΩ	
	channels (1)	3.7		$I_S = 100 \text{ mA}$		3					
		4.3				3					
		1.8				300	400		450		
		2.5 V _O = 0 V to	$V_S = 0 V to$		130	170		230			
R_{FLAT}	ON resistance flatness (2)	3	1.65 - 4.8	V _{CC}		90	120		170	mΩ	
		3.7		$I_S = 100 \text{ mA}$		90	120		170		
		4.3				90	120		170		
I _{OFF}	Sn OFF state leakage current	1.65 - 4.8	1.65 - 4.8	$V_S = 0$ to V_{CC} $V_D = 0$ to V_{CC}	-20		20	-300	300	nA	
I _{ON}	Sn ON state leakage current	1.65 - 4.8	1.65 - 4.8	$V_S = 0$ to V_{CC} $V_D = open$	-20		20	-100	100	nA	

Electrical characteristics STG4259

Table 6. DC specifications (continued)

I _D	D ON state leakage current	1.65 - 4.8	1.65 - 4.8	V_S = open V_D = 0 to V_{CC}	-20	20	-100	100	nA
Icc	Quiescent supply current	1.65- 4.8	1.65 - 4.8	V _{SEL} = V _{CC} or GND	- 0.05	0.05	-0.2	0.2	μΑ
I _{SEL}	SEL leakage current	1.65- 4.8	1.65 - 4.8	V _{SEL} = 4.3V or GND	-0.1	0.1	-1	1	μА

^{1.} $\Delta R_{ON} = R_{ON(Max)} - R_{ON(Min)}$

Table 7. AC electrical characteristics ($C_L = 35 \text{ pF}, R_L = 50 \Omega, t_r = t_f \le 5 \text{ ns}$)

		7	Test cond		,		Value										
Symbol	Parameter	V _{cc}	V_{L}		T,	_A = 25°	С	-40 to	85°C	Uni t							
		(V)	(V)		Min	Тур	Max	Min	Max								
		1.65 - 1.95				0.13											
t _{PLH} ,	Propagation delay	2.3 - 2.7	1.65 - 4.8			0.15				ns							
t _{PHL}	uelay	3.0 - 3.3	4.0			0.16											
		3.6 - 4.3				0.16											
		1.65 - 1.95		$V_S = V_{CC}$		95	123		95								
t _{ON}	Turn-ON time	2.3 - 2.7	1.65 - 4.8	$R_L = 50 \Omega$		48	62		70	ns							
	ume	3 - 3.6		4.8	4.8	4.8	4.8	$C_L = 30 \text{ pF}$		33	43		55				
		4.3				29	38		40								
		1.65 - 1.95	1.65 - 4.8	1.05 -	V _S = V _{CC}		12	15		70							
t _{OFF}	Turn-OFF time	2.3 - 2.7			1.05 -	1.05 -	1.05 -	1.05 -	1.05 -	1.05 -	1.05 - D	1.05 - D - 50 0		12	16		55
	unie	3 - 3.6		$C_L = 30 pF$		13	17		40								
		4.3				13	17		35								
	Break-	1.65 - 1.95		C _L = 35 pF	10	66											
t _D	before-make	2.3 - 2.7	1.65 - 4.8	$R_L = 50 \Omega$	10	28				ns							
	time delay	3 - 3.6	4.0	$V_S = V_{CC}/2$	10	18											
		4.3			10	12											
		1.65- 1.95				86											
Q	Charge injection	2.3-2.7	1.65- 4.8	$C_L = 1nF$		95				рС							
	ingeodon	3.0-3.3	4.8	4.8 V _{GEN}	$V_{GEN} = 0V$		98										
		3.6-4.3				103											

^{2.} Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal ranges.

Table 8. Analog switch characteristics ($C_L = 5pF$, $R_L = 50\Omega$, $T_A = 25$ °C)

		-	Test conditions				Value			
Symbol	Parameter	V _{CC}	V_{L}		T,	_A = 25°	С	-40 to	85°C	Unit
		(V)	(V)		Min	Тур	Max	Min	Max	
O _{IRR}	OFF isolation (1)	1.65 - 4.3	4.3	$V_S = 1V_{RMS}$ f = 100kHz		-71				dB
Xtalk	Crosstalk	1.6 - 4.3	4.3	$V_S = 1V_{RMS}$ f = 100 kHz		-93				dB
T _{HD}	Total harmonic distortion	2.3 - 4.3	4.3	$R_L = 600 \Omega$ $C_L = 50 \text{ pF}$ $V_S = V_{CC} V_{PP}$ $f = 600 \text{Hz} \text{ to}$ 20 kHz		0.01				%
BW	-3dB bandwidth (switch ON)	1.65 - 4.3	4.3	R _L = 50Ω		40				MHz
C _{SEL}	Control pin input capacitance	1.8 - 4.3	1.8 - 4.3	V _L = V _{CC}		30				pF
C _{Sn}	Sn port capacitance	1.8 - 4.3	1.8 - 4.3	$V_L = V_{CC}$		95				pF
C _D	D port capacitance when switch is enabled	1.8 - 4.3	1.8 - 4.3	$V_L = V_{CC}$		230				pF

^{1.} OFF-isolation = 20 log_{10} (VD/VS), V_D = output, V_S = input to off switch

Test circuits STG4259

4 Test circuits

Figure 4. ON resistance

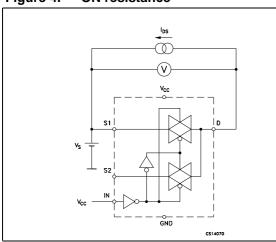


Figure 5. Bandwidth

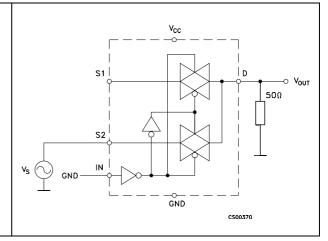


Figure 6. OFF leakage

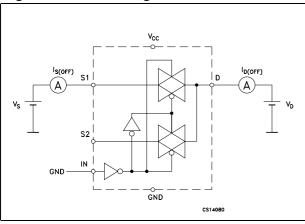


Figure 7. Channel-to-channel crosstalk

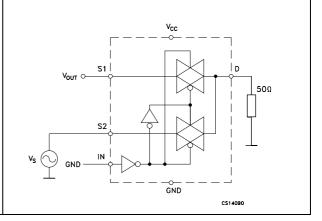
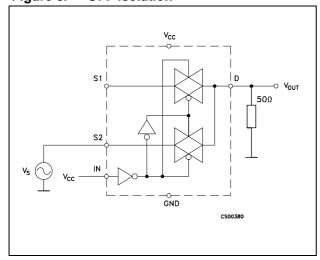


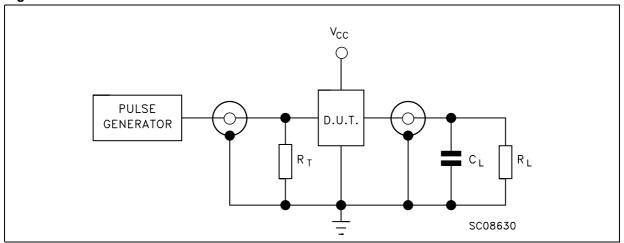
Figure 8. OFF isolation



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STG4259 Test circuits

Figure 9. Test circuit

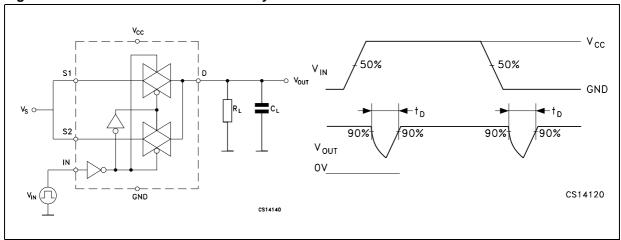


Note: 1 $C_L = 5/35$ pF or equivalent: (includes jig capacitance)

2 $R_L = 50\Omega$ or equivalent

3 R_T = Z_{OUT} of pulse generator (typically 50Ω)

Figure 10. Break-before-make time delay



Test circuits STG4259

Figure 11. Switching time and charge injection $(V_{GEN}=0V,\,R_{GEN}=0\Omega,\,R_L=1M\Omega,\,C_L=100pF)$

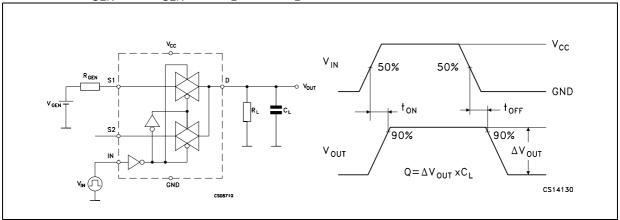
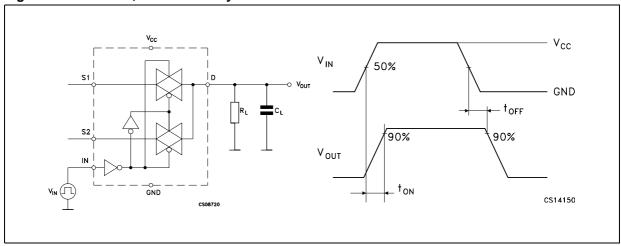


Figure 12. Turn ON, turn OFF delay time



5 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Figure 13. Flip-Chip11 package outline

1. Drawing not to scale.

Table 9. Flip-Chip11 mechanical data

Dim.	С	ata book (mm	1)		Drawing (mm))
Dim.	Min	Тур	Max	Min	Тур	Max
А	0.585	0.65	0.715	0.60	0.65	0.70
A1	0.21	0.25	0.29	0.22	0.25	0.28
A2		0.4		0.38	0.4	0.42
b	0.265	0.315	0.365	0.290	0.315	0.340
D	1.518	1.568	1.618	1.553	1.568	1.583
D1		1		0.99	1	1.01
Е	2.018	2.068	2.118	2.083	2.068	2.118
E1		1.5		1.49	1.5	1.51
е	0.45	0.5	0.55	0.46	0.5	0.54
f		0.284		0.272	0.284	0.292
ccc		0.08			0.08	

The terminal A1 on the bumps side is identified by a distinguishing feature (for instance by a circular "clear area" - typically 0.1 mm diameter) and/or a missing bump. The terminal A1 on the backside of the product is identified by a distinguishing feature (for instance by a circular "dot" - typically 0.5 mm diameter).

Figure 14. Foot print recommendations

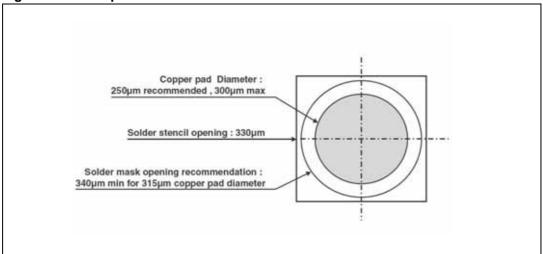


Figure 15. Marking

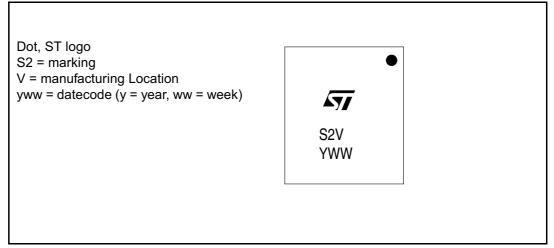
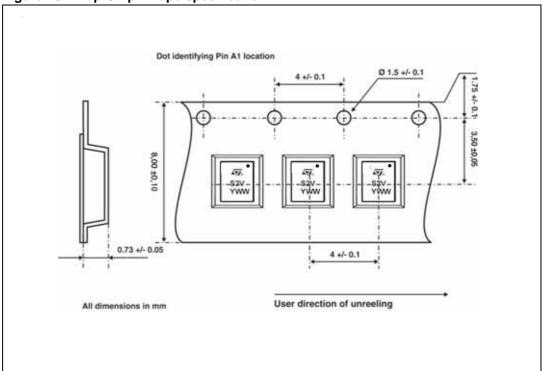


Figure 16. Flip-Chip11 tape specification



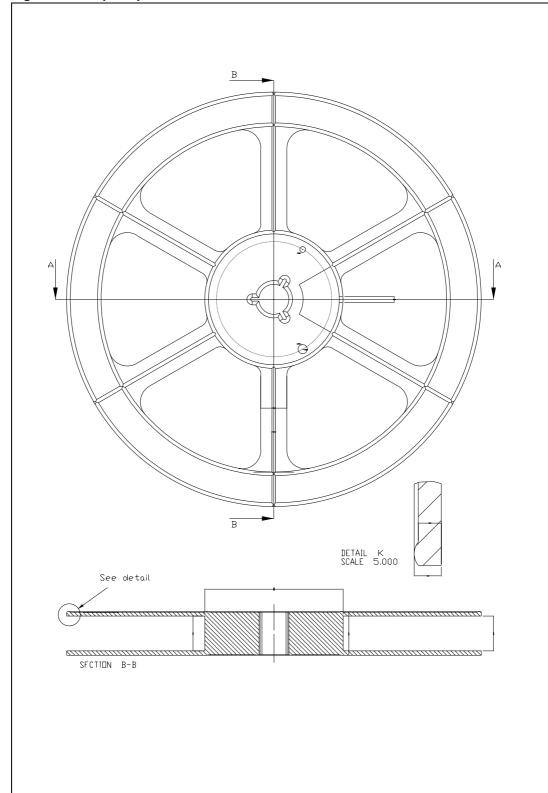


Figure 17. Flip-Chip11 reel information

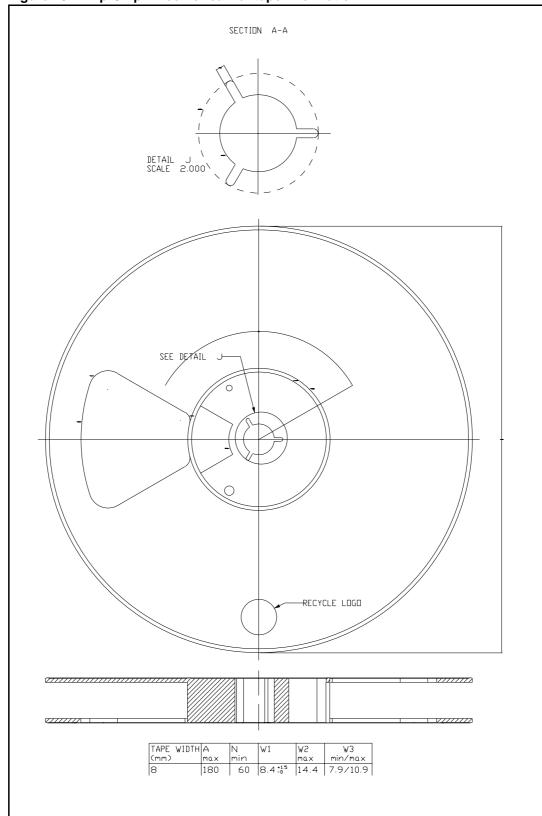


Figure 18. Flip-Chip11 reel for carrier tape information

Revision history STG4259

6 Revision history

Table 10. Document revision history

Date	Revision	Changes			
03-Oct-2006	1	First release			
16-Oct-2006	2	Schematic Figure 1 on page 3 updated			
07-Aug-2007	3	Air discharge ESD rating updated			
28-Aug-2007	4	Changed Figure 16 on page 15			

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